PROGETTO SPARC:

MAIN RESULTS OBTAINED IN LECCE

METALLIC PHOTOCATHODES

- METALLIC PHOTOCATHODES FOR CONVENTIONAL RF GUNS; (Mg, Y, Cu, Zn...);
- METALLIC PHOTOCATHODES FOR HYBRID SUPERCONDUCTING RF GUNS. (Nb, Pb...)

Mg THIN FILMS-BASED PHOTOCATHODES PREPARED BY PLD TECHNIQUE

- Mg THIN FILMS DEPOSITED ON DIFFERENT SUBSTRATES;
- CHARACTERIZATION AND TESTING OF PHOTOCATHODES IN PHOTODIODE CELL;
- FINAL TESTING IN A REAL PHOTOINJECTOR GUN.

Y THIN FILMS-BASED PHOTOCATHODES PREPARED BY PLD TECHNIQUE

- Y THIN FILMS DEPOSITED ON DIFFERENT SUBSTRATES;
- CHARACTERIZATION AND TESTING OF PHOTOCATHODES IN PHOTODIODE CELL;
- FINAL TESTING IN A REAL PHOTOINJECTOR GUN.

MAIN RESULTS

- 1. QEs of metallic thin films (Mg, Y) are comparable to those of the bulk;
- 2. Surface contamination is a big problem even with metallic films though less drastic than that observed with semiconductor cathodes;
 - 2
 - 3. H chemisorption is the main process responsible of surface

contamination at vacuum levels less than 10 Pa;

- 2
- 4. H O chemisorption is the main surface process in the SPARC gun due to the soft baking procedure (temperature <120 ℃);
- 5. Protective coating is needless; the native metal oxide forms in open air becomes the natural protecting coating of the film surface;

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SUPERCONDUCTING RF GUNS

- ADVANTAGES
- HIGHER ACCELERATING
 GRADIENT
- LOWER DISSIPATED POWER
- LOWER THERMAL EMITTANCE

- DRAWBACKS
- LOW QE OF Nb CATHODE

• EXPENSIVE SYSTEM

HIGH TECHNOLOGY IS
 REQUIRED

PROPERTIES OF CATHODES FOR SRF-GUNS

- HIGH QUALITY FACTOR OF SC CAVITY;
 - RESPECTABLE QE;
- HIGH SUPERCONDUCTING TEMPERATURE.

• PROBLEMS

TO ADDRESS THIS CONCERN...

- PHOTOCATHODES BASED ON Pb THIN FILMS DEPOSITED ON Nb BY PLD TECHNIQUE.
 - WHY Pb?
 - HIGH SUPERCONDUCTING TEMPERATURE;
 - RELATIVELY HIGH QE;
 - GOOD CHEMICAL STABILITY.
 - WHY PLD?
 - FILMS ADHERENT TO THE SUBSTRATE

APPROACH TO THE PROBLEM

• THREE DIFFERENT STEPS

- 1. OPTIMAZATION OF DEPOSITION PROCESS OF Pb THIN FILMS BY PLD;
- 1. MEASUREMENT OF THE PHOTOEMISSIVE PROPERTIES OF Nb/Pb PHOTOCATHODES;
- 1. INSTALLATION OF THE PHOTOCATHODES IN A REAL SRF CAVITY.

CONCLUSION SO FAR

- METALLIC PHOTOCATHODES SUFFER THE SURFACE CONTAMINATION;
- LASER CLEANING PROCESS IS MANDATORY TO RECOVER PHOTOCATHODES;
- PHOTOCATHODES BASED ON Y THIN FILM SEEM TO BE THE MOST PROMISING;
- IT HAS BEEN SHOWN, **DEFINITIVELY**, THAT THE MOST SUITABLE FILM DEPOSITION TECHNIQUE IS THE PLD TECHNIQUE;
- THE PREPARATION OF CATHODES IS THE WEAK POINT OF SRF-GUNS.

Do ut des

- LASER Nd:YAG E BANCO OTTICO;
- 3 ASSEGNI DI RICERCA;
- 1 BORSA BIENNALE PER RICERCATORE STRANIERO.
- 22 ARTICOLI PUBBLICATI IN RIVISTE INTERNAZIONALI DAL 2005;
- 12 PRESENTAZIONI A CONFERENZE INTERNAZIONALI.

Pubblicazioni collegate al progetto SPARC dal 2011

- 1) A. Lorusso, V. Fasano, A. Perrone and K. Lovchinov, "Y thin films grown by pulsed laser ablation", J. Vac. Sci. & Technol. 29 (2011) 031502-5
- 1) A. Lorusso, F. Gontad, and A. Perrone, "In-situ and ex-situ investigations of pulsed laser ablation of Y target", Thin Solid Films, 520 (2011) 117 120
- 1) A. Lorusso, L. Cultrera, V. Fasano, and A. Perrone, "*Detailed studies of photocathodes based on Y thin films grown by PLD technique*", Nucl. Instr. and Meth. in Phys. Res. B, 269 (2011) 3091–3093
- A. Lorusso, F. Gontad, A. Perrone, "Deposition of MgF₂ Thin Films by Pulsed Laser Ablation Technique", Jpn. J. Appl. Phys. 50 (2011) 08JD071-3
- 1) A. Lorusso, F. Gontad, A. Perrone, N. Stankova, "*Highlights on photocathodes based on thin films prepared by pulsed laser deposition*", Physical Review Special Topics Accelerators and Beams, 14 (2011) 090401-9
- 1) F. Gontad, A. Lorusso, and A. Perrone, "Structure and morphology of laser-ablated Pb thin films", Thin Solid Films, 520 (2012) 3892-3895
- 1) F. Gontad, A. Lorusso, A. Perrone, "Detailed mass spectrometric studies during laser ablation of Yttrium target in high vacuum", Thin Solid Films, 520 (2012) 5211-5214
- 1) A. Lorusso, M. L. De Giorgi, C. Fotakis, P. Miglietta, B. Maiolo, P. Miglietta, E. L. Papadopoulou, A. Perrone, "Y thin films by ultra-short pulsed laser deposition for photocathode application", Appl. Surf. Sci. http://dx.doi.org/10.1016/j.apsusc.2012.05.080

RF PHOTOCATHODE GUN – SLAC/BNL/ UCLA/SPARC

- Maximum electric field: 120 MV/m
- RF pulse duration: 4.5 µs
- Peak power at 120 MVolt/m: 15 MW
- Operating vacuum: 10⁻⁷ Pa
- Operating temperature: 45 °C
- Laser incidence angle at the cathode: 72°
- RF: 2.856 GHz
- Electron bunch energy at the exit: 5.6 MeV

DRIVE LASER SYSTEM

- Ti:Sapphire
- Wavelength: 800 nm
- Laser pulse duration: 100 fs
- Laser pulse energy @ 266 nm: 0,5 mJ
- Repetition rate: 1-10 Hz
- Pointing stability on cathode: < 0,1 mm
- Flat top uniformity (peak to peak): < 30%

LINAC

- LENGTH: 3 m;
- **REPETITION FREQUENCY: 100 Hz;**
- BUNCH CHARGE: 1 nC;
- BUNCH CURRENT: 100 A;
- BUNCH DURATION: 10 ps
- ELECTRON ENERGY AT THE EXIT: 150 MeV.

UNDULATOR

- Undulator period: 2,8 cm
- Undulator sections: 6
- Undulator section length: 2,16 m
- Saturation length: 12 m
- Wavelength: 500 nm
- Pulse duration: 3 ps
- Power @ saturation > 80 MW
- Bunch charge: 1 nC
- Photons/pulse: 10¹⁵

ELECTRON BEAM

- Electron energy beam: 150 MeV
- Bunch charge: 1 nC
- Electric field: 120 MV/m
- Photocathode spot size: 1.1 mm
- Beam pulse duration: 10 ps
- Bunch energy at gun exit: 5.6 MeV
- Bunch peak current at linac exit: 100 A
- Normalized transverse emittance at linac exit: <2 µmrad
- Beam spot size at linac exit: 0.4 mm
- Bunch length at linac exit: 1 mm
- Relative energy spread: <0.1 %



SPARX

• ELECTRON BEAM

- Electron beam energy: 1.2 2.4 GeV
- Electron charge: 1 nC
- Peak current: 1 2.5 kA
- Emittance: 1 µmrad



SPARX

- FEL RADIATION
- Wavelength: 1.5 13.5 nm;
- Brillanza: 10³² CU (phtons/s/0,1%bw/(µmrad)²);
- Potenza: 10 GW;
- Pulse duration: 0,1 ps;
- Energy: 1 mJ.